Amplifier Transistor PNP Silicon

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCE	-25	Vdc
Collector–Base Voltage	V _{CB}	-25	Vdc
Emitter-Base Voltage	VEB	-4.0	Vdc
Collector Current — Continuous	IC	-200	mAdc
Total Power Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	TJ, Tstg	-55 to +150	°C



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THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage ($I_C = -1.0 \text{ mA}, I_B = 0$)	V(BR)CEO	-25	_	Vdc
Collector–Base Breakdown Voltage $(I_{C} = -10 \ \mu\text{A}, I_{E} = 0)$	V _(BR) CBO	-25	_	Vdc
Emitter–Base Breakdown Voltage ($I_C = 0, I_E = -10 \mu A$)	V _{(BR)EBO}	-4.0	_	Vdc
Collector Cutoff Current ($V_{CB} = -20 \text{ V}, \text{ Ig} = 0$)	ІСВО	_	-50	nAdc
Emitter Cutoff Current ($V_{EB} = -3.0 \text{ V}, I_{C} = 0$)	IEBO	_	-50	nAdc

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ELECTRICAL CHARACTERISTICS (T _A =	25°C unless otherwise noted) (Continued)
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Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain $(I_C = -2.0 \text{ mA}, V_{CE} = -1.0 \text{ V})$ $(I_C = -50 \text{ mA}, V_{CE} = -1.0 \text{ V})$	hFE	120 60	360 —	—
Collector–Emitter Saturation Voltage $(I_C = -50 \text{ mA}, I_B = -5.0 \text{ mA})$	V _{CE(sat)}	_	-0.4	Vdc
Base–Emitter Saturation Voltage $(I_{C} = -50 \text{ mA}, I_{B} = -5.0 \text{ mA})$	V _{BE(sat)}	_	-0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS	•			
Current–Gain — Bandwidth Product ($I_C = -10 \text{ mA}, V_{CE} = -20 \text{ V}, f = 100 \text{ MHz}$)	fT	170	_	MHz
Output Capacitance $(V_{CB} = -5.0 \text{ V}, I_E = 0, f = 1.0 \text{ MHz})$	C _{ob}	_	4.5	pF
Input Capacitance ($V_{EB} = -0.5 \text{ V}, I_C = 0, f = 1.0 \text{ MHz}$)	C _{ib}	_	11.5	pF
Small–Signal Current Gain ($I_C = -2.0 \text{ mA}$, $V_{CE} = 1.0 \text{ V}$, f = 1.0 kHz)	h _{fe}	120	480	—
Noise Figure (I _C = $-100 \ \mu$ A, V _{CE} = $-5.0 \ V$, R _S = $1.0 \ k\Omega$, f = $1.0 \ kHz$)	NF	_	4.0	dB

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PACKAGE DIMENSIONS

CASE 029-04 (TO-226AA) ISSUE AD





SECTION X-X

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 4. DIMENSION F APPLIES BETWEEN I AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
V	0.135		3.43	

STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR

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